

# Micropower Dual CMOS Voltage Comparator

## NCV2393, TS393

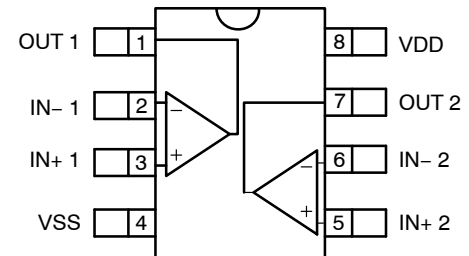
The NCV2393 and TS393 are micropower CMOS dual voltage comparators. They feature extremely low consumption of 6  $\mu$ A typical per comparator and operate over a wide temperature range of  $T_A = -40$  to  $125^\circ\text{C}$ . The NCV2393 and TS393 are available in an SOIC-8 package.

### Features

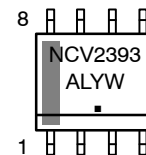
- Extremely Low Supply Current: 6  $\mu$ A Typical Per Channel
- Wide Supply Range: 2.7 to 16 V
- Extremely Low Input Bias Current: 1 pA Typical
- Extremely Low Input Offset Current: 1 pA Typical
- Input Common Mode Range Includes  $V_{SS}$
- High Input Impedance:  $10^{12} \Omega$
- Pin-to-Pin Compatibility with Dual Bipolar LM393
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



### PIN CONNECTIONS



### MARKING DIAGRAM



- A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
■ = Pb-Free Package

### ORDERING INFORMATION

| Device      | Package             | Shipping <sup>†</sup>  |
|-------------|---------------------|------------------------|
| NCV2393DR2G | SOIC-8<br>(Pb-Free) | 2,500 /<br>Tape & Reel |
| TS393DR2G   | SOIC-8<br>(Pb-Free) | 2,500 /<br>Tape & Reel |

<sup>†</sup> For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, [BRD8011/D](#).

# NCV2393, TS393

## PIN DESCRIPTION

| Pin | Name  | Type   | Description                                                                          |
|-----|-------|--------|--------------------------------------------------------------------------------------|
| 1   | OUT 1 | Output | Output of comparator 1. The open-drain output requires an external pull-up resistor. |
| 2   | IN- 1 | Input  | Inverting input of comparator 1                                                      |
| 3   | IN+ 1 | Input  | Non-inverting input of comparator 1                                                  |
| 4   | VSS   | Power  | Negative supply                                                                      |
| 5   | IN+ 2 | Input  | Non-inverting input of comparator 2                                                  |
| 6   | IN- 2 | Input  | Inverting input of comparator 2                                                      |
| 7   | OUT 2 | Output | Output of comparator 2. The open-drain output requires an external pull-up resistor. |
| 8   | VDD   | Power  | Positive supply                                                                      |

## ABSOLUTE MAXIMUM RATINGS (Note 1)

Over operating free-air temperature, unless otherwise stated

| Parameter                                 | Limit | Unit |
|-------------------------------------------|-------|------|
| Supply Voltage, $V_S$ ( $V_{DD}-V_{SS}$ ) | 18    | V    |

## INPUT AND OUTPUT PINS

|                                               |          |    |
|-----------------------------------------------|----------|----|
| Input Voltage (Note 2)                        | 18       | V  |
| Input Differential Voltage, $V_{ID}$ (Note 3) | $\pm 18$ | V  |
| Input Current (through ESD protection diodes) | 50       | mA |
| Output Voltage                                | 18       | V  |
| Output Current                                | 20       | mA |

## TEMPERATURE

|                      |             |    |
|----------------------|-------------|----|
| Storage Temperature  | -65 to +150 | °C |
| Junction Temperature | 150         | °C |

## ESD RATINGS

|                  |      |   |
|------------------|------|---|
| Human Body Model | 1500 | V |
| Machine Model    | 50   | V |

## LATCH-UP RATINGS

|                  |     |    |
|------------------|-----|----|
| Latch-up Current | 100 | mA |
|------------------|-----|----|

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Stresses beyond the absolute maximum ratings can lead to reduced reliability and damage.
2. Excursions of input voltages may exceed the power supply level. As long as the common mode voltage [ $V_{CM} = (V_{IN+} + V_{IN-})/2$ ] remains within the specified range, the comparator will provide a stable output state. However, the maximum current through the ESD diodes of the input stage must strictly be observed.
3. Input differential voltage is the non-inverting input terminal with respect to the inverting input terminal. To prevent damage to the gates, each comparator includes back-to-back zener diodes between input terminals. When differential voltage exceeds 6.2 V, the diodes turn on. Input resistors of 1 k $\Omega$  have been integrated to limit the current in this event.
4. This device series incorporates ESD protection and is tested by the following methods:  
ESD Human Body Model tested per AEC-Q100-002 (JEDEC standard: JESD22-A114)  
ESD Machine Model tested per AEC-Q100-003 (JEDEC standard: JESD22-A115)  
Latch-up Current tested per JEDEC standard: JESD78.

## THERMAL INFORMATION (Note 5)

| Symbol        | Thermal Metric               | Value | Unit |
|---------------|------------------------------|-------|------|
| $\theta_{JA}$ | Junction-to-Ambient (Note 6) | 190   | °C/W |
| $\Psi_{JT}$   | Junction-to-Case Top         | 107   | °C/W |

5. Short-circuits can cause excessive heating and destructive dissipation. Values are typical.
6. Multilayer board, 1 oz. copper, 400 mm<sup>2</sup> copper area, both junctions heated equally

# NCV2393, TS393

## OPERATING CONDITIONS

| Symbol | Parameter                            | Limit       | Unit |
|--------|--------------------------------------|-------------|------|
| $V_S$  | Supply Voltage ( $V_{DD} - V_{SS}$ ) | +2.7 to +16 | V    |
| $T_A$  | Operating Free Air Temperature Range | -40 to +125 | °C   |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## ELECTRICAL CHARACTERISTICS: $V_S = +3\text{ V}$

(**Boldface** limits apply over the specified temperature range,  $T_A = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , guaranteed by characterization and/or design.)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------|-----------|------------|-----|-----|-----|------|
|--------|-----------|------------|-----|-----|-----|------|

### INPUT CHARACTERISTICS

|          |                               |                                                       |                            |     |                                |    |
|----------|-------------------------------|-------------------------------------------------------|----------------------------|-----|--------------------------------|----|
| $V_{OS}$ | Offset Voltage                | $V_{CM} = \text{mid-supply}$                          |                            | 1.4 | 13                             | mV |
|          |                               |                                                       |                            |     | <b>14</b>                      | mV |
| $I_{IB}$ | Input Bias Current (Note 7)   | $V_{CM} = \text{mid-supply}$                          |                            | 1   |                                | pA |
|          |                               |                                                       |                            |     | <b>600</b>                     | pA |
| $I_{OS}$ | Input Offset Current (Note 7) | $V_{CM} = \text{mid-supply}$                          |                            | 1   |                                | pA |
|          |                               |                                                       |                            |     | <b>300</b>                     | pA |
| $V_{CM}$ | Input Common Mode Range       |                                                       | $V_{SS}$                   |     | $V_{DD} - 1.5$                 | V  |
|          |                               |                                                       | <b><math>V_{SS}</math></b> |     | <b><math>V_{DD} - 2</math></b> | V  |
| CMRR     | Common Mode Rejection Ratio   | $V_{CM} = V_{SS}$ to $V_{CM} = V_{DD} - 1.5\text{ V}$ |                            | 70  |                                | dB |

### OUTPUT CHARACTERISTICS

|          |                     |                                                  |  |                |                                  |    |
|----------|---------------------|--------------------------------------------------|--|----------------|----------------------------------|----|
| $V_{OL}$ | Output Voltage Low  | $V_{ID} = -1\text{ V}$ , $I_{OL} = +6\text{ mA}$ |  | $V_{SS} + 300$ | $V_{SS} + 450$                   | mV |
|          |                     |                                                  |  |                | <b><math>V_{SS} + 700</math></b> | mV |
| $I_{OH}$ | Output Current High | $V_{ID} = +1\text{ V}$ , $V_{OH} = +3\text{ V}$  |  | 2              | 40                               | nA |
|          |                     |                                                  |  |                | <b>1000</b>                      | nA |

### DYNAMIC PERFORMANCE

|           |                               |                                                                                                                 |                |  |     |  |               |
|-----------|-------------------------------|-----------------------------------------------------------------------------------------------------------------|----------------|--|-----|--|---------------|
| $t_{PLH}$ | Propagation Delay Low to High | $V_{CM} = \text{mid-supply}$ ,<br>$f = 10\text{ kHz}$ , $R_{PU} = 5.1\text{ k}\Omega$ ,<br>$C_L = 50\text{ pF}$ | 5 mV overdrive |  | 2.1 |  | $\mu\text{s}$ |
|           |                               |                                                                                                                 | TTL input      |  | 0.6 |  | $\mu\text{s}$ |
| $t_{PHL}$ | Propagation Delay High to Low | $V_{CM} = \text{mid-supply}$ ,<br>$f = 10\text{ kHz}$ , $R_{PU} = 5.1\text{ k}\Omega$ ,<br>$C_L = 50\text{ pF}$ | 5 mV overdrive |  | 3.9 |  | $\mu\text{s}$ |
|           |                               |                                                                                                                 | TTL input      |  | 0.2 |  | $\mu\text{s}$ |

### POWER SUPPLY

|          |                              |                                      |  |    |           |               |
|----------|------------------------------|--------------------------------------|--|----|-----------|---------------|
| PSRR     | Power Supply Rejection Ratio | $V_S = +3\text{ V}$ to $+5\text{ V}$ |  | 70 |           | dB            |
| $I_{DD}$ | Quiescent Current            | Per channel, no load, output = LOW   |  | 6  | 15        | $\mu\text{A}$ |
|          |                              |                                      |  |    | <b>20</b> | $\mu\text{A}$ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

7. Guaranteed by characterization and/or design.

# NCV2393, TS393

**ELECTRICAL CHARACTERISTICS:**  $V_S = +5\text{ V}$ , unless otherwise noted

(**Boldface** limits apply over the specified temperature range,  $T_A = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , guaranteed by characterization and/or design.)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------|-----------|------------|-----|-----|-----|------|
|--------|-----------|------------|-----|-----|-----|------|

## INPUT CHARACTERISTICS

|          |                                  |                                                                   |                            |     |                                |    |
|----------|----------------------------------|-------------------------------------------------------------------|----------------------------|-----|--------------------------------|----|
| $V_{OS}$ | Offset Voltage                   | $V_{CM} = \text{mid-supply V, } V_S = 5\text{ V to } 10\text{ V}$ |                            | 1.4 | 13                             | mV |
|          |                                  |                                                                   |                            |     | <b>14</b>                      | mV |
| $I_{IB}$ | Input Bias Current<br>(Note 8)   | $V_{CM} = \text{mid-supply}$                                      |                            | 1   |                                | pA |
|          |                                  |                                                                   |                            |     | <b>600</b>                     | pA |
| $I_{OS}$ | Input Offset Current<br>(Note 8) | $V_{CM} = \text{mid-supply}$                                      |                            | 1   |                                | pA |
|          |                                  |                                                                   |                            |     | <b>300</b>                     | pA |
| $V_{CM}$ | Input Common Mode Range          |                                                                   | $V_{SS}$                   |     | $V_{DD} - 1.5$                 | V  |
|          |                                  |                                                                   | <b><math>V_{SS}</math></b> |     | <b><math>V_{DD} - 2</math></b> | V  |
| CMRR     | Common Mode Rejection Ratio      | $V_{CM} = V_{SS}$ to $V_{CM} = V_{DD} - 1.5\text{ V}$             |                            | 71  |                                | dB |

## OUTPUT CHARACTERISTICS

|          |                     |                                                |  |                |                                  |    |
|----------|---------------------|------------------------------------------------|--|----------------|----------------------------------|----|
| $V_{OL}$ | Output Voltage Low  | $V_{ID} = -1\text{ V, } I_{OL} = +6\text{ mA}$ |  | $V_{SS} + 260$ | $V_{SS} + 350$                   | mV |
|          |                     |                                                |  |                | <b><math>V_{SS} + 550</math></b> | mV |
| $I_{OH}$ | Output Current High | $V_{ID} = +1\text{ V, } V_{OH} = +5\text{ V}$  |  | 2              | 40                               | nA |
|          |                     |                                                |  |                | <b>1000</b>                      | nA |

## DYNAMIC PERFORMANCE

|            |                               |                                                                                                    |                 |  |     |  |               |
|------------|-------------------------------|----------------------------------------------------------------------------------------------------|-----------------|--|-----|--|---------------|
| $t_{FALL}$ | Fall Time                     | 50 mV overdrive, $f = 10\text{ kHz}$ , $R_{PU} = 5.1\text{ k}\Omega$ , $C_L = 50\text{ pF}$        |                 |  | 25  |  | ns            |
| $t_{PLH}$  | Propagation Delay Low to High | $V_{CM} = \text{mid-supply, } f = 10\text{ kHz, } R_{PU} = 5.1\text{ k}\Omega, C_L = 50\text{ pF}$ | 5 mV overdrive  |  | 2.1 |  | $\mu\text{s}$ |
|            |                               |                                                                                                    | 10 mV overdrive |  | 1.2 |  | $\mu\text{s}$ |
|            |                               |                                                                                                    | 20 mV overdrive |  | 0.8 |  | $\mu\text{s}$ |
|            |                               |                                                                                                    | 40 mV overdrive |  | 0.5 |  | $\mu\text{s}$ |
|            |                               |                                                                                                    | TTL input       |  | 0.6 |  | $\mu\text{s}$ |
| $t_{PHL}$  | Propagation Delay High to Low | $V_{CM} = \text{mid-supply, } f = 10\text{ kHz, } R_{PU} = 5.1\text{ k}\Omega, C_L = 50\text{ pF}$ | 5 mV overdrive  |  | 5.8 |  | $\mu\text{s}$ |
|            |                               |                                                                                                    | 10 mV overdrive |  | 3.2 |  | $\mu\text{s}$ |
|            |                               |                                                                                                    | 20 mV overdrive |  | 1.7 |  | $\mu\text{s}$ |
|            |                               |                                                                                                    | 40 mV overdrive |  | 1.0 |  | $\mu\text{s}$ |
|            |                               |                                                                                                    | TTL input       |  | 0.3 |  | $\mu\text{s}$ |

## POWER SUPPLY

|          |                              |                                      |  |    |           |               |
|----------|------------------------------|--------------------------------------|--|----|-----------|---------------|
| PSRR     | Power Supply Rejection Ratio | $V_S = +5\text{ V to } +10\text{ V}$ |  | 80 |           | dB            |
| $I_{DD}$ | Quiescent Current            | Per channel, no load, output = LOW   |  | 6  | 15        | $\mu\text{A}$ |
|          |                              |                                      |  |    | <b>20</b> | $\mu\text{A}$ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

8. Guaranteed by characterization and/or design

TYPICAL OPERATING CHARACTERISTICS

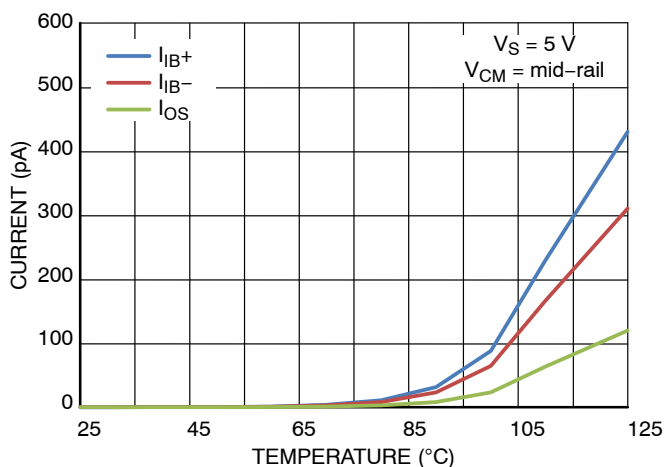


Figure 1.  $I_B$  and  $I_{OS}$  vs. Temperature

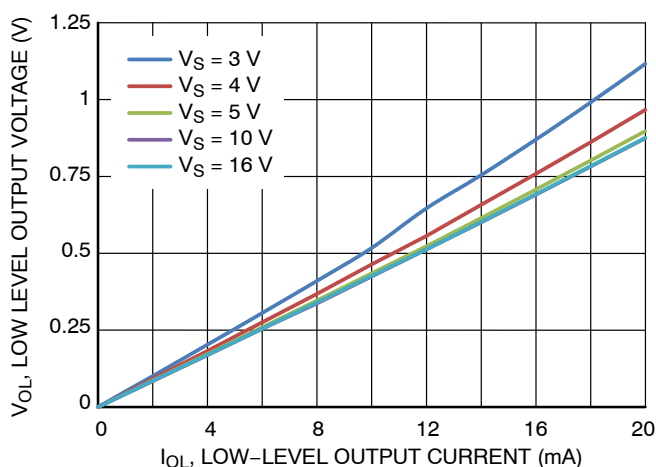


Figure 2.  $V_{OL}$  vs.  $I_{OL}$

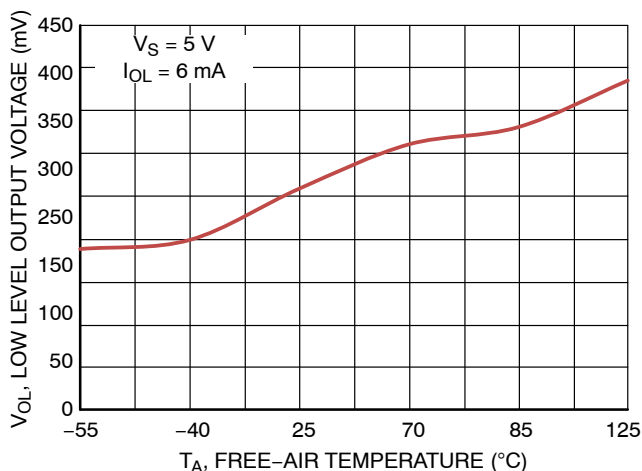


Figure 3.  $V_{OL}$  vs. Temperature

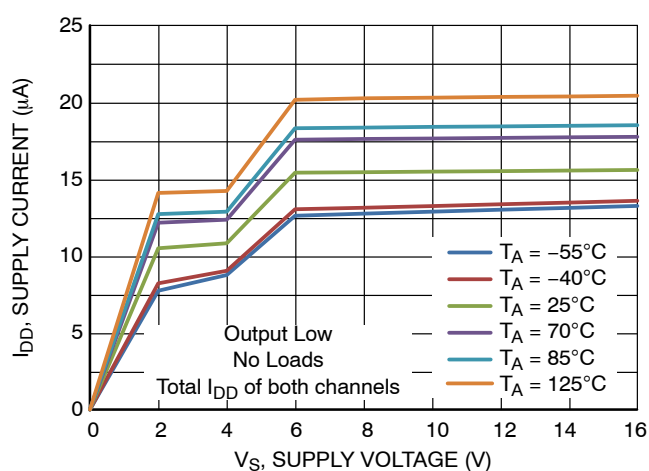


Figure 4.  $I_{DD}$  vs.  $V_S$

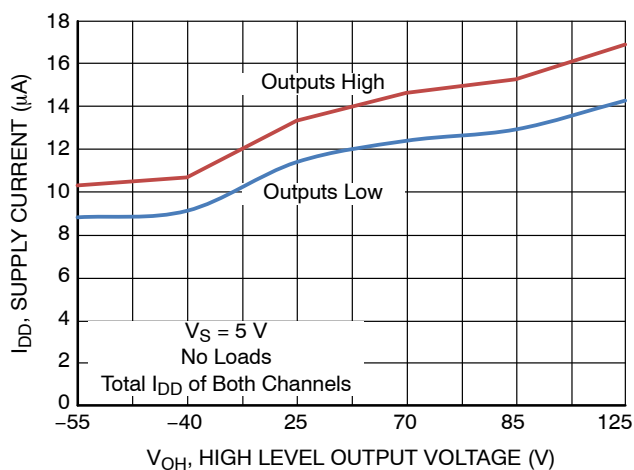


Figure 5.  $I_{DD}$  vs. Temperature

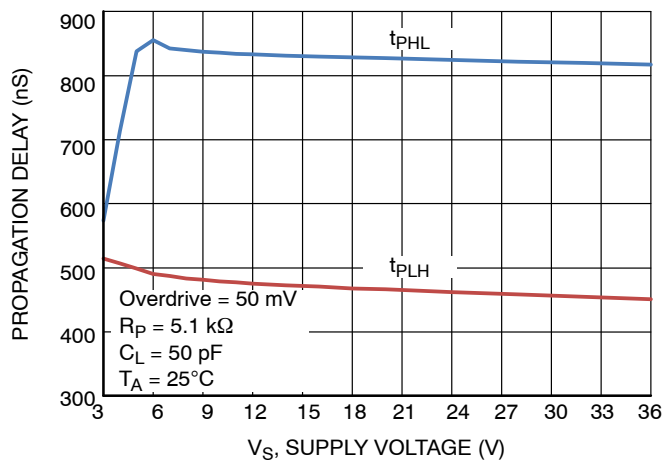


Figure 6. Propagation Delay vs.  $V_S$

TYPICAL OPERATING CHARACTERISTICS (continued)

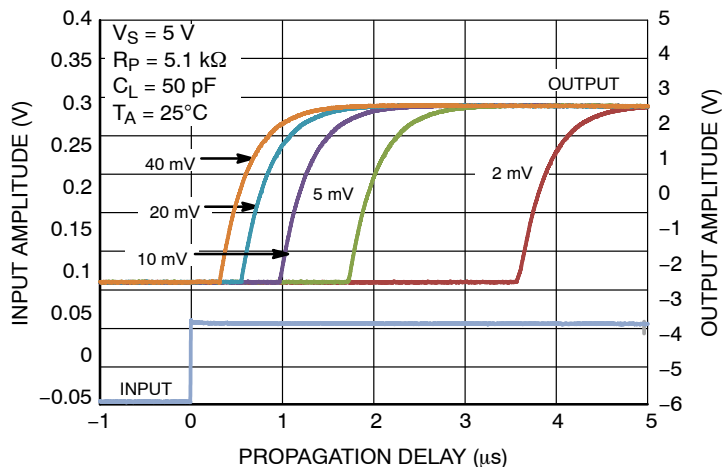


Figure 7.  $t_{pLH}$  vs. Overdrive

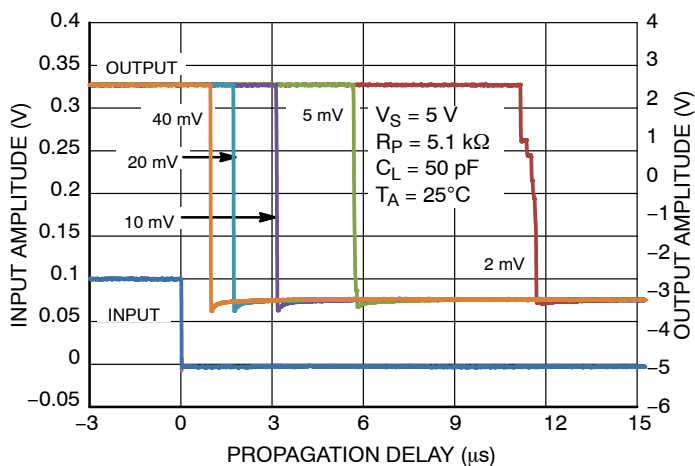


Figure 8.  $t_{pHL}$  vs. Overdrive

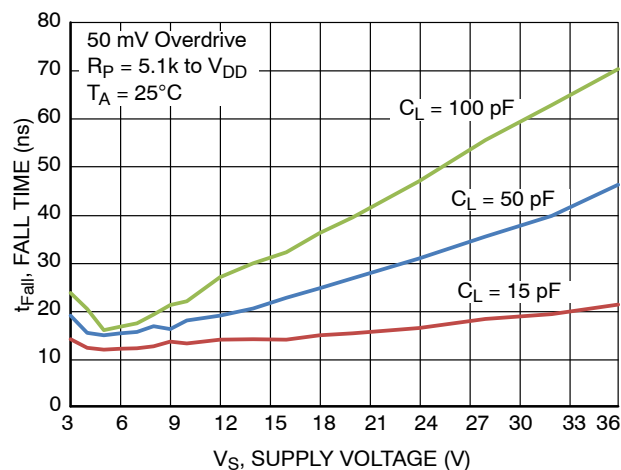


Figure 9. Fall Time vs.  $V_S$

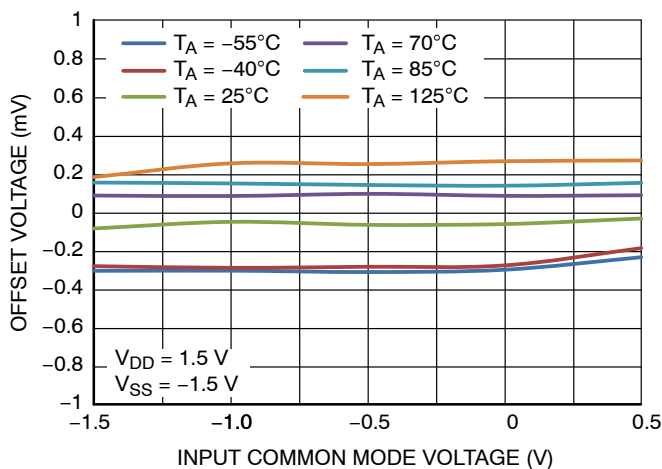


Figure 10.  $V_{OS}$  vs.  $V_{CM}$  ( $V_S = 3 V$ )

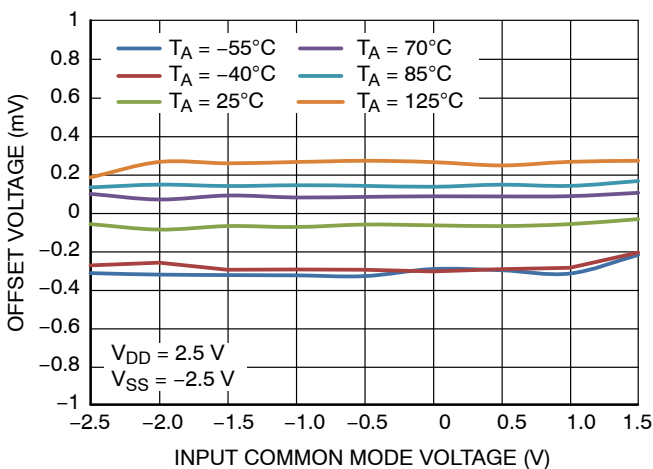
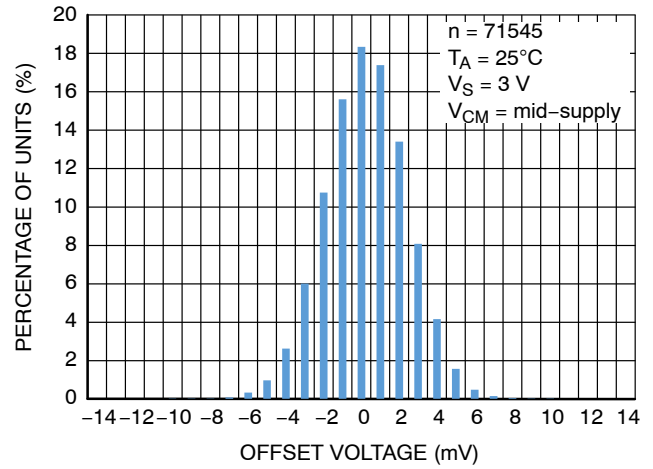
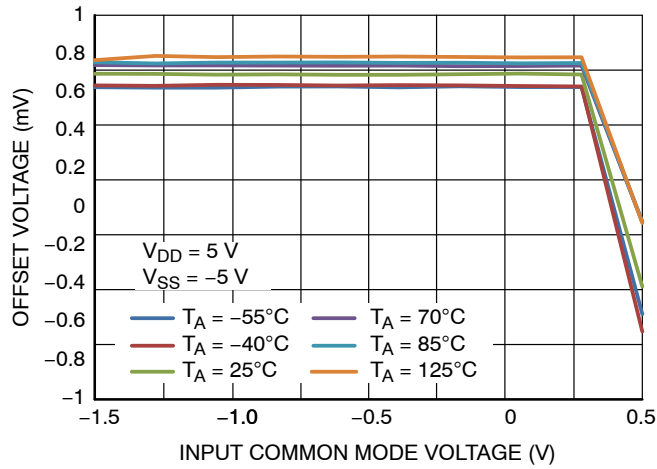


Figure 11.  $V_{OS}$  vs.  $V_{CM}$  ( $V_S = 5 V$ )

TYPICAL OPERATING CHARACTERISTICS (continued)

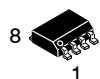


## NCV2393, TS393

### REVISION HISTORY

| Revision | Description of Changes                            | Date      |
|----------|---------------------------------------------------|-----------|
| 6        | Rebranded the Data Sheet to <b>onsemi</b> format. | 5/20/2025 |

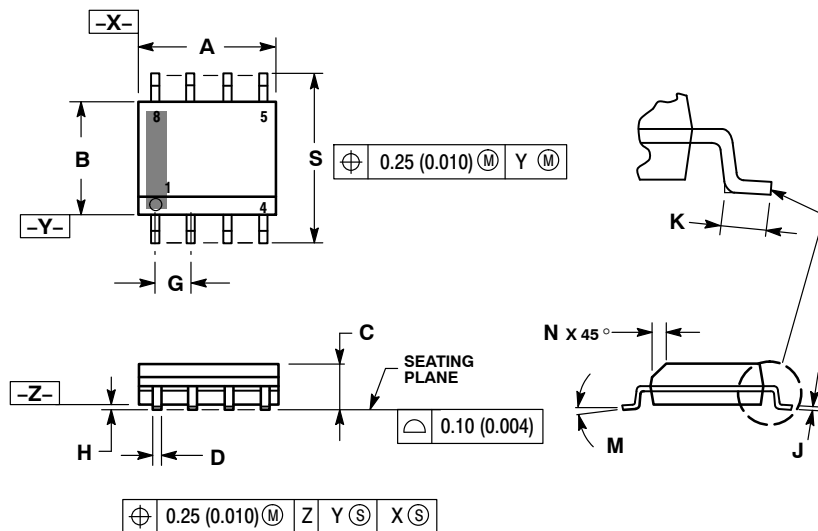




SCALE 1:1

**SOIC-8 NB**  
CASE 751-07  
ISSUE AK

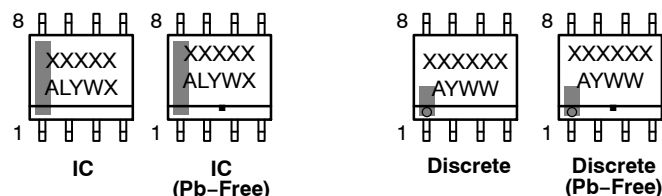
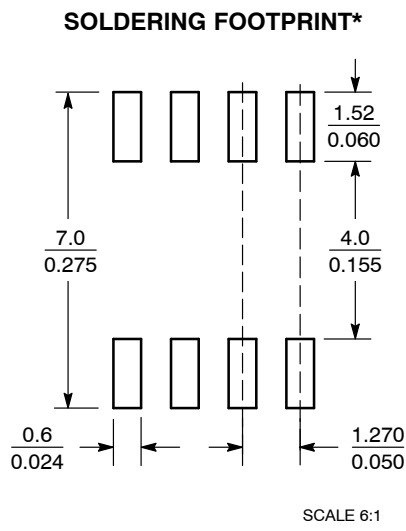
DATE 16 FEB 2011



## NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 4.80        | 5.00 | 0.189     | 0.197 |
| B   | 3.80        | 4.00 | 0.150     | 0.157 |
| C   | 1.35        | 1.75 | 0.053     | 0.069 |
| D   | 0.33        | 0.51 | 0.013     | 0.020 |
| G   | 1.27 BSC    |      | 0.050 BSC |       |
| H   | 0.10        | 0.25 | 0.004     | 0.010 |
| J   | 0.19        | 0.25 | 0.007     | 0.010 |
| K   | 0.40        | 1.27 | 0.016     | 0.050 |
| M   | 0°          | 8°   | 0°        | 8°    |
| N   | 0.25        | 0.50 | 0.010     | 0.020 |
| S   | 5.80        | 6.20 | 0.228     | 0.244 |

**GENERIC**  
**MARKING DIAGRAM\***


XXXXXX = Specific Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

XXXXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
WW = Work Week  
▪ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**STYLES ON PAGE 2**

|                         |                    |                                                                                                                                                                                     |
|-------------------------|--------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>DOCUMENT NUMBER:</b> | <b>98ASB42564B</b> | Electronic versions are uncontrolled except when accessed directly from the Document Repository.<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| <b>DESCRIPTION:</b>     | <b>SOIC-8 NB</b>   | <b>PAGE 1 OF 2</b>                                                                                                                                                                  |

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

**SOIC-8 NB**  
**CASE 751-07**  
**ISSUE AK**

DATE 16 FEB 2011

|                                                                                                                                                                                                   |                                                                                                                                                                                          |                                                                                                                                                                                    |                                                                                                                                                                                                        |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>STYLE 1:</b><br>PIN 1. EMITTER<br>2. COLLECTOR<br>3. COLLECTOR<br>4. EMITTER<br>5. EMITTER<br>6. BASE<br>7. BASE<br>8. EMITTER                                                                 | <b>STYLE 2:</b><br>PIN 1. COLLECTOR, DIE, #1<br>2. COLLECTOR, #1<br>3. COLLECTOR, #2<br>4. COLLECTOR, #2<br>5. BASE, #2<br>6. EMITTER, #2<br>7. BASE, #1<br>8. EMITTER, #1               | <b>STYLE 3:</b><br>PIN 1. DRAIN, DIE #1<br>2. DRAIN, #1<br>3. DRAIN, #2<br>4. DRAIN, #2<br>5. GATE, #2<br>6. SOURCE, #2<br>7. GATE, #1<br>8. SOURCE, #1                            | <b>STYLE 4:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. ANODE<br>4. ANODE<br>5. ANODE<br>6. ANODE<br>7. ANODE<br>8. COMMON CATHODE                                                                           |
| <b>STYLE 5:</b><br>PIN 1. DRAIN<br>2. DRAIN<br>3. DRAIN<br>4. DRAIN<br>5. GATE<br>6. GATE<br>7. SOURCE<br>8. SOURCE                                                                               | <b>STYLE 6:</b><br>PIN 1. SOURCE<br>2. DRAIN<br>3. DRAIN<br>4. SOURCE<br>5. SOURCE<br>6. GATE<br>7. GATE<br>8. SOURCE                                                                    | <b>STYLE 7:</b><br>PIN 1. INPUT<br>2. EXTERNAL BYPASS<br>3. THIRD STAGE SOURCE<br>4. GROUND<br>5. DRAIN<br>6. GATE 3<br>7. SECOND STAGE Vd<br>8. FIRST STAGE Vd                    | <b>STYLE 8:</b><br>PIN 1. COLLECTOR, DIE #1<br>2. BASE, #1<br>3. BASE, #2<br>4. COLLECTOR, #2<br>5. COLLECTOR, #2<br>6. EMITTER, #2<br>7. EMITTER, #1<br>8. COLLECTOR, #1                              |
| <b>STYLE 9:</b><br>PIN 1. EMITTER, COMMON<br>2. COLLECTOR, DIE #1<br>3. COLLECTOR, DIE #2<br>4. EMITTER, COMMON<br>5. EMITTER, COMMON<br>6. BASE, DIE #2<br>7. BASE, DIE #1<br>8. EMITTER, COMMON | <b>STYLE 10:</b><br>PIN 1. GROUND<br>2. BIAS 1<br>3. OUTPUT<br>4. GROUND<br>5. GROUND<br>6. BIAS 2<br>7. INPUT<br>8. GROUND                                                              | <b>STYLE 11:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. SOURCE 2<br>4. GATE 2<br>5. DRAIN 2<br>6. DRAIN 2<br>7. DRAIN 1<br>8. DRAIN 1                                               | <b>STYLE 12:</b><br>PIN 1. SOURCE<br>2. SOURCE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN                                                                                 |
| <b>STYLE 13:</b><br>PIN 1. N.C.<br>2. SOURCE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN                                                                              | <b>STYLE 14:</b><br>PIN 1. N-SOURCE<br>2. N-GATE<br>3. P-SOURCE<br>4. P-GATE<br>5. P-DRAIN<br>6. P-DRAIN<br>7. N-DRAIN<br>8. N-DRAIN                                                     | <b>STYLE 15:</b><br>PIN 1. ANODE 1<br>2. ANODE 1<br>3. ANODE 1<br>4. ANODE 1<br>5. CATHODE, COMMON<br>6. CATHODE, COMMON<br>7. CATHODE, COMMON<br>8. CATHODE, COMMON               | <b>STYLE 16:</b><br>PIN 1. EMITTER, DIE #1<br>2. BASE, DIE #1<br>3. EMITTER, DIE #2<br>4. BASE, DIE #2<br>5. COLLECTOR, DIE #2<br>6. COLLECTOR, DIE #2<br>7. COLLECTOR, DIE #1<br>8. COLLECTOR, DIE #1 |
| <b>STYLE 17:</b><br>PIN 1. VCC<br>2. V2OUT<br>3. V1OUT<br>4. TXE<br>5. RXE<br>6. VEE<br>7. GND<br>8. ACC                                                                                          | <b>STYLE 18:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. CATHODE<br>8. CATHODE                                                                 | <b>STYLE 19:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. SOURCE 2<br>4. GATE 2<br>5. DRAIN 2<br>6. MIRROR 2<br>7. DRAIN 1<br>8. MIRROR 1                                             | <b>STYLE 20:</b><br>PIN 1. SOURCE (N)<br>2. GATE (N)<br>3. SOURCE (P)<br>4. GATE (P)<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN                                                                   |
| <b>STYLE 21:</b><br>PIN 1. CATHODE 1<br>2. CATHODE 2<br>3. CATHODE 3<br>4. CATHODE 4<br>5. CATHODE 5<br>6. COMMON ANODE<br>7. COMMON ANODE<br>8. CATHODE 6                                        | <b>STYLE 22:</b><br>PIN 1. I/O LINE 1<br>2. COMMON CATHODE/VCC<br>3. COMMON CATHODE/VCC<br>4. I/O LINE 3<br>5. COMMON ANODE/GND<br>6. I/O LINE 4<br>7. I/O LINE 5<br>8. COMMON ANODE/GND | <b>STYLE 23:</b><br>PIN 1. LINE 1 IN<br>2. COMMON ANODE/GND<br>3. COMMON ANODE/GND<br>4. LINE 2 IN<br>5. LINE 2 OUT<br>6. COMMON ANODE/GND<br>7. COMMON ANODE/GND<br>8. LINE 1 OUT | <b>STYLE 24:</b><br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR/ANODE<br>4. COLLECTOR/ANODE<br>5. CATHODE<br>6. CATHODE<br>7. COLLECTOR/ANODE<br>8. COLLECTOR/ANODE                                      |
| <b>STYLE 25:</b><br>PIN 1. VIN<br>2. N/C<br>3. REXT<br>4. GND<br>5. IOUT<br>6. IOUT<br>7. IOUT<br>8. IOUT                                                                                         | <b>STYLE 26:</b><br>PIN 1. GND<br>2. dv/dt<br>3. ENABLE<br>4. ILIMIT<br>5. SOURCE<br>6. SOURCE<br>7. SOURCE<br>8. VCC                                                                    | <b>STYLE 27:</b><br>PIN 1. ILIMIT<br>2. OVLO<br>3. UVLO<br>4. INPUT+<br>5. SOURCE<br>6. SOURCE<br>7. SOURCE<br>8. DRAIN                                                            | <b>STYLE 28:</b><br>PIN 1. SW_TO_GND<br>2. DASIC_OFF<br>3. DASIC_SW_DET<br>4. GND<br>5. V_MON<br>6. VBULK<br>7. VBULK<br>8. VIN                                                                        |
| <b>STYLE 29:</b><br>PIN 1. BASE, DIE #1<br>2. EMITTER, #1<br>3. BASE, #2<br>4. EMITTER, #2<br>5. COLLECTOR, #2<br>6. COLLECTOR, #2<br>7. COLLECTOR, #1<br>8. COLLECTOR, #1                        | <b>STYLE 30:</b><br>PIN 1. DRAIN 1<br>2. DRAIN 1<br>3. GATE 2<br>4. SOURCE 2<br>5. SOURCE 1/DRAIN 2<br>6. SOURCE 1/DRAIN 2<br>7. SOURCE 1/DRAIN 2<br>8. GATE 1                           |                                                                                                                                                                                    |                                                                                                                                                                                                        |

|                         |                    |                                                                                                                                                                                     |
|-------------------------|--------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>DOCUMENT NUMBER:</b> | <b>98ASB42564B</b> | Electronic versions are uncontrolled except when accessed directly from the Document Repository.<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| <b>DESCRIPTION:</b>     | <b>SOIC-8 NB</b>   | <b>PAGE 2 OF 2</b>                                                                                                                                                                  |

**onsemi** and **onsemi** are trademarks of Semiconductor Components Industries, LLC dba **onsemi** or its subsidiaries in the United States and/or other countries. **onsemi** reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights nor the rights of others.

**onsemi**, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## ADDITIONAL INFORMATION

### TECHNICAL PUBLICATIONS:

Technical Library: [www.onsemi.com/design/resources/technical-documentation](http://www.onsemi.com/design/resources/technical-documentation)  
onsemi Website: [www.onsemi.com](http://www.onsemi.com)

### ONLINE SUPPORT: [www.onsemi.com/support](http://www.onsemi.com/support)

For additional information, please contact your local Sales Representative at  
[www.onsemi.com/support/sales](http://www.onsemi.com/support/sales)